

TECHNICAL DATA DATA SHEET 6090, REV -

HERMETIC ULTRA FAST SOFT RECOVERY RECTIFIER

Features:

- Low forward voltage drop
- Low power loss, high efficiency
- Very high surge capacity
- Soft reverse recovery at low and high temperature
- Trr guaranteed lower than 40 nsec
- Electrically / mechanically stable during and after packaging

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	300	V
Max. Average Forward Current	I _{F(AV)}	50% duty cycle, rectangular wave form, T _C = 65 °C	25	А
Max. Peak One Cycle Non- Repetitive Surge Current	IFSM	8.3 msec, sine pulse	300	Α
Thermal Impedance	Z _{TH}	T _C = 25 °C	1.3	°C / W
Max. Junction Temperature	TJ	-	- 65 to + 150	°C
Max. Storage Temperature	T _{stg}	-	- 65 to + 150	°C

Electrical Characteristics:

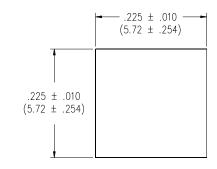
Characteristics	Symbol	Condition	Тур.	Max.	Units
Max. Forward Voltage Drop	V _{F1}	@ 10A, Pulse, T _J = 25 °C	0.92	0.99	V
		@ 25A, Pulse, T _J = 25 °C	1.02	1.12	
	V _{F2}	@ 10A, Pulse, T _J = 125 °C	-	0.92	V
		@ 25A, Pulse, T _J = 125 °C	-	1.05	
	I _{R1}	@V _R = 300V, Pulse, T _J = 25 °C	2	30	μΑ
Max. Reverse Current	I _{R2}	@V _R = 300V, Pulse, T _J = 125 °C	-	500	μΑ
Reverse Recovery Time	t _{RR}	$I_F = 0.5A$; $I_R = 1.0A$, $I_{RM} = 0.25A$	35	40	nsec
		T _J = 25 °C			
Max. Junction Capacitance	Ст	@V _R = 10V, T _C = 25 °C	400	-	pF
		$f_{SIG} = 1MHz$, $I_{SIG} = 100mV$ (p-p)			

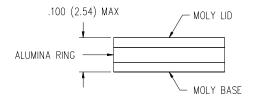
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MECHANICAL DIMENSIONS: In Inches / mm

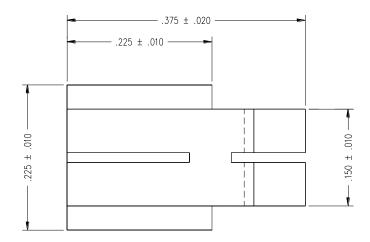
*Dimensions shown are with solder dipping.

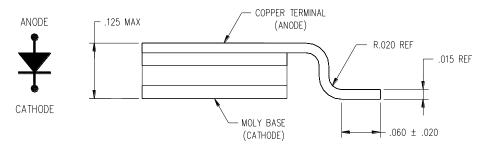
SHD-1 HIGH PROFILE





SHD-1B HIGH PROFILE

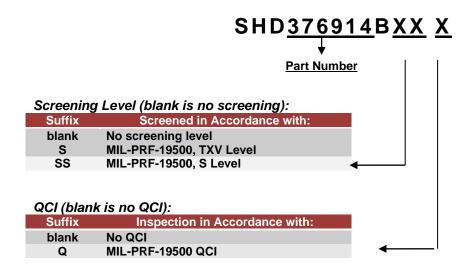






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